

Power Schottky rectifier

Features

- Negligible switching losses
- Low forward voltage drop
- Surface mount miniature packages
- Avalanche capability specified

Description

Axial and surface mount power Schottky rectifiers suited to switched mode power supplies and high frequency DC to DC converters.

Packaged in SMA, STmite flat and DO-41, this device is especially intended for use in low voltage, high frequency inverters and small battery chargers.

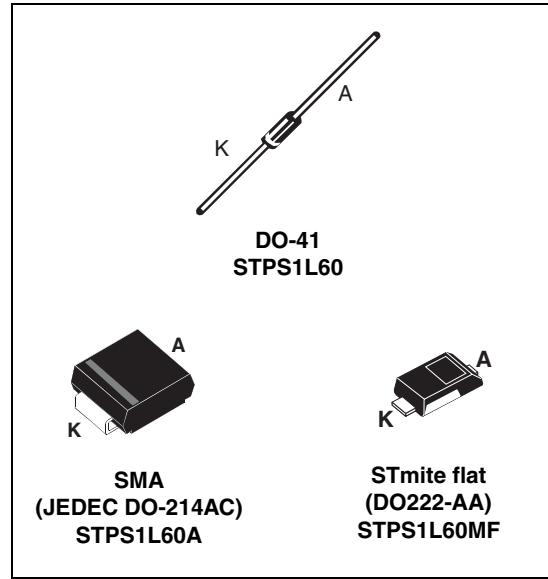


Table 1. Device summary

Symbol	Value
$I_{F(AV)}$	1 A
V_{RRM}	60 V
T_j (max)	150 °C
V_F (max)	0.56 V

1 Characteristics

Table 2. Absolute ratings (limiting values)

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage			60	V
$I_{F(RMS)}$	Forward rms current	SMA flat		2	A
		SMA, DO-41		10	A
$I_{F(AV)}$	Average forward current	SMA	$T_L = 130^\circ\text{C} \delta = 0.5$	1	A
		DO-41	$T_L = 120^\circ\text{C} \delta = 0.5$		
		STmite flat	$T_C = 135^\circ\text{C} \delta = 0.5$		
I_{FSM}	Surge non repetitive forward current	$t_p = 10\text{ ms sinusoidal}$		40	A
P_{ARM}	Repetitive peak avalanche power	$t_p = 1\text{ }\mu\text{s } T_j = 25^\circ\text{C}$		1200	W
T_{stg}	Storage temperature range			- 65 to + 150	$^\circ\text{C}$
T_j	Maximum operating junction temperature ⁽¹⁾			150	$^\circ\text{C}$
dV/dt	Critical rate of rise of reverse voltage			10000	V/ μs

1. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter			Value	Unit
$R_{th(j-a)}$	Junction to ambient		SMA	120	$^\circ\text{C/W}$
		Lead length = 10 mm	DO-41	100	
$R_{th(j-l)}$	Junction to lead		SMA	30	$^\circ\text{C/W}$
		Lead length = 10 mm	DO-41	45	
$R_{th(j-c)}$	Junction to case		STmite flat	20	$^\circ\text{C/W}$

Table 4. Static electrical characteristics

Symbol	Parameter	Tests conditions	Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$		50	μA
		$T_j = 100^\circ\text{C}$		1.5	5	mA
$V_F^{(1)}$	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 1\text{ A}$		0.57	V
		$T_j = 100^\circ\text{C}$			0.56	
		$T_j = 125^\circ\text{C}$		0.5	0.54	
		$T_j = 25^\circ\text{C}$	$I_F = 2\text{ A}$		0.75	
		$T_j = 100^\circ\text{C}$			0.68	
		$T_j = 125^\circ\text{C}$		0.6	0.66	

1. Pulse test: $t_p = 380\text{ }\mu\text{s}, \delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.44 \times I_{F(AV)} + 0.12 I_F^2 (RMS)$$

Figure 1. Average forward power dissipation versus average forward current

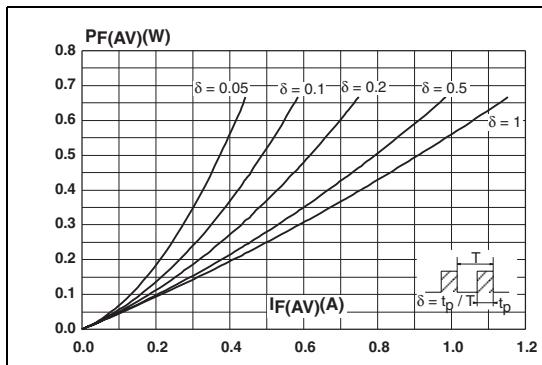


Figure 3. Average forward current versus ambient temperature ($\delta = 0.5$) (DO-41)

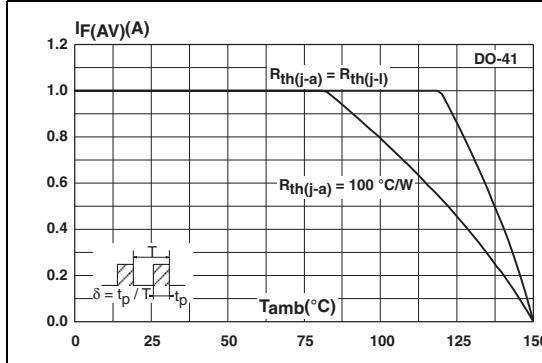


Figure 5. Normalized avalanche power derating versus pulse duration

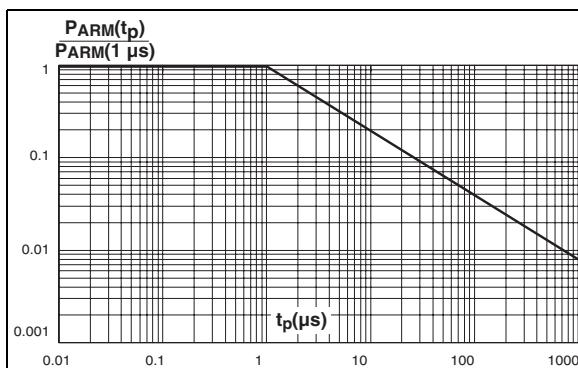


Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$) (SMA)

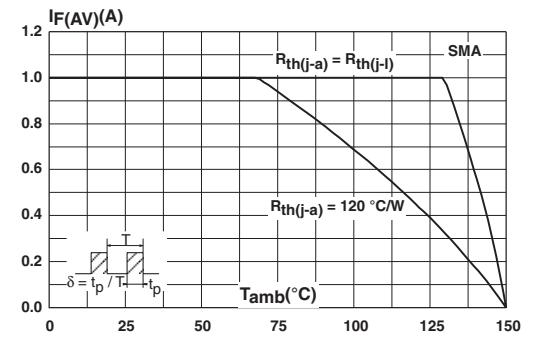


Figure 4. Average forward current versus ambient temperature ($\delta = 0.5$) (STmite flat)

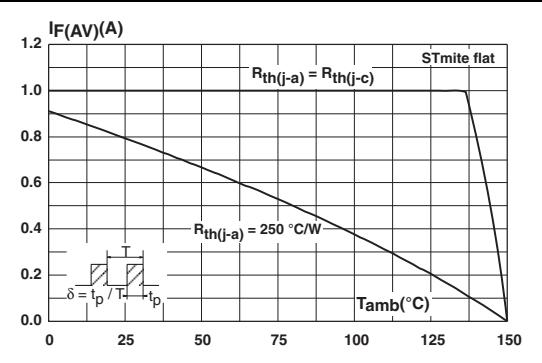


Figure 6. Normalized avalanche power derating versus junction temperature

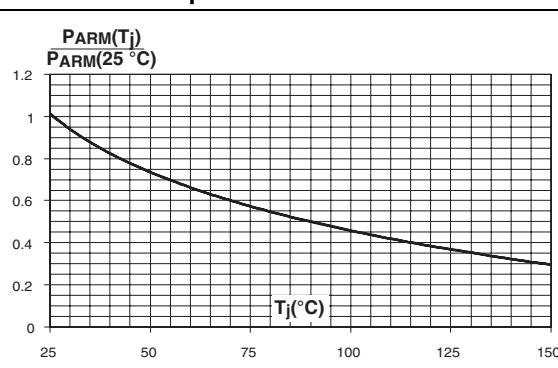


Figure 7. Non repetitive surge peak forward current versus overload duration (maximum values) (SMA)

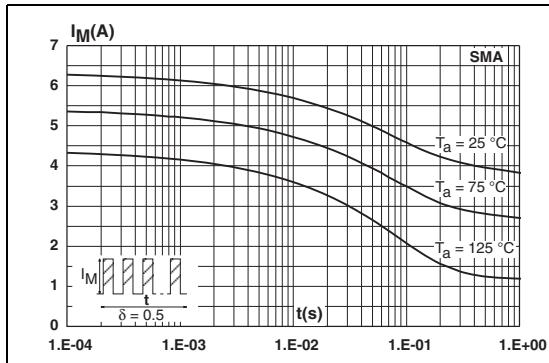


Figure 8. Non repetitive surge peak forward current versus overload duration (maximum values) (DO-41)

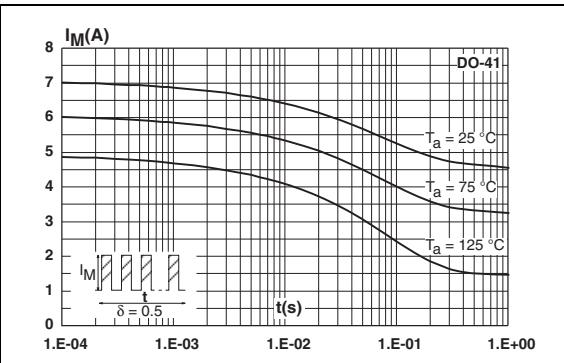


Figure 9. Non repetitive surge peak forward current versus overload duration (maximum values) (STmite flat)

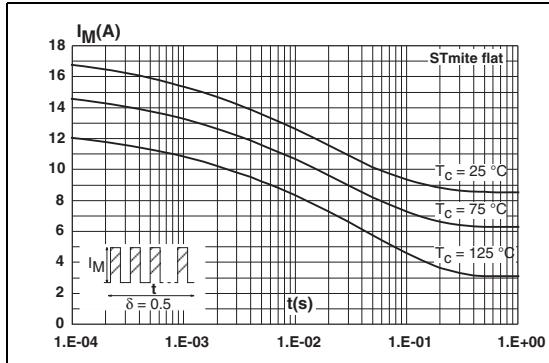


Figure 10. Relative variation of thermal impedance junction to ambient versus pulse duration (SMA)

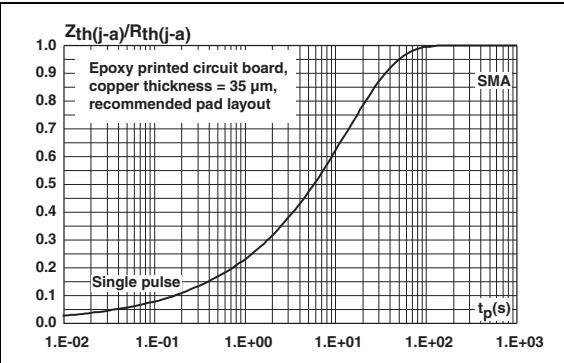


Figure 11. Relative variation of thermal impedance junction to ambient versus pulse duration (DO-41)

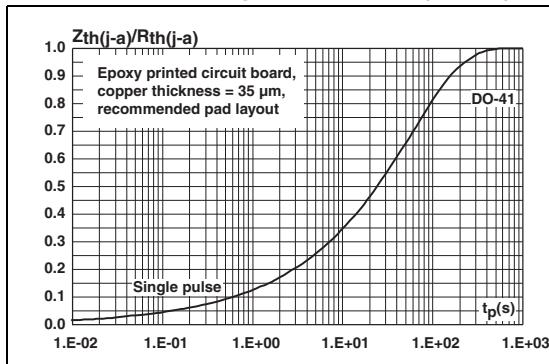


Figure 12. Relative variation of thermal impedance junction to ambient versus pulse duration (STmite flat)

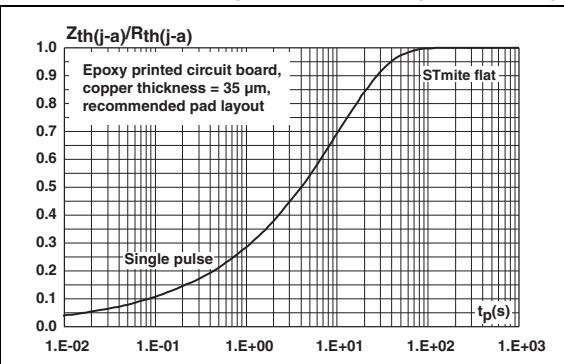


Figure 13. Reverse leakage current versus reverse voltage applied (typical values)

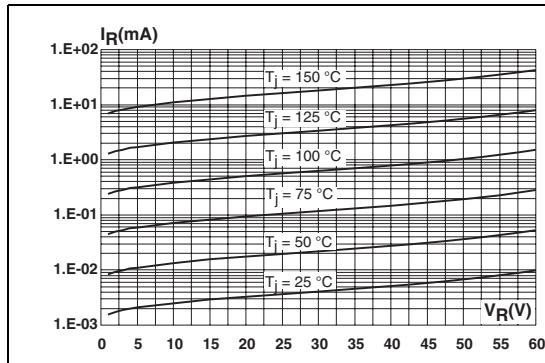


Figure 14. Junction capacitance versus reverse voltage applied (typical values)

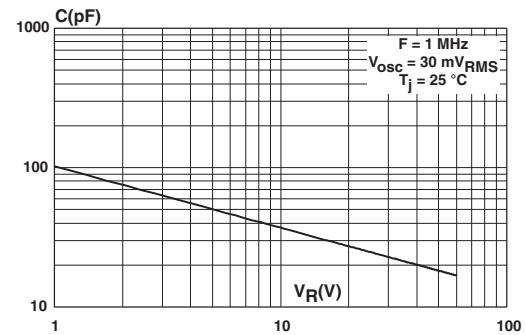


Figure 15. Forward voltage drop versus forward current (typical values, high level)

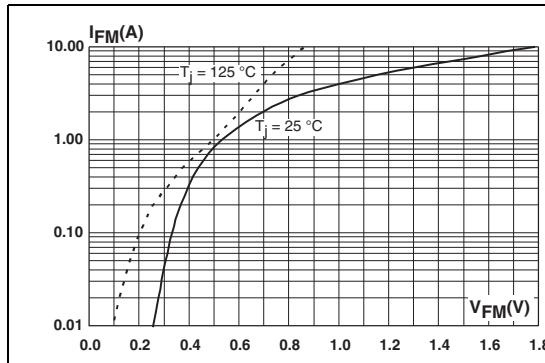


Figure 16. Forward voltage drop versus forward current (typical values, low level)

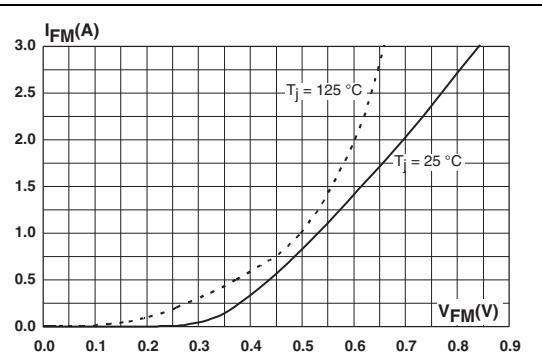


Figure 17. Thermal resistance junction to ambient versus copper surface under each lead (SMA)

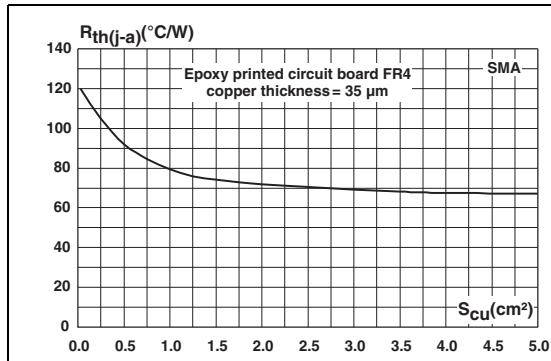


Figure 18. Thermal resistance versus lead length (DO-41)

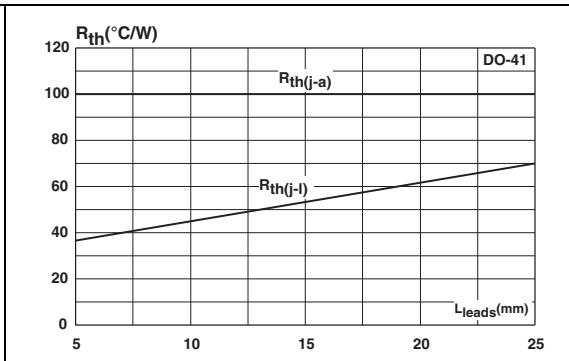
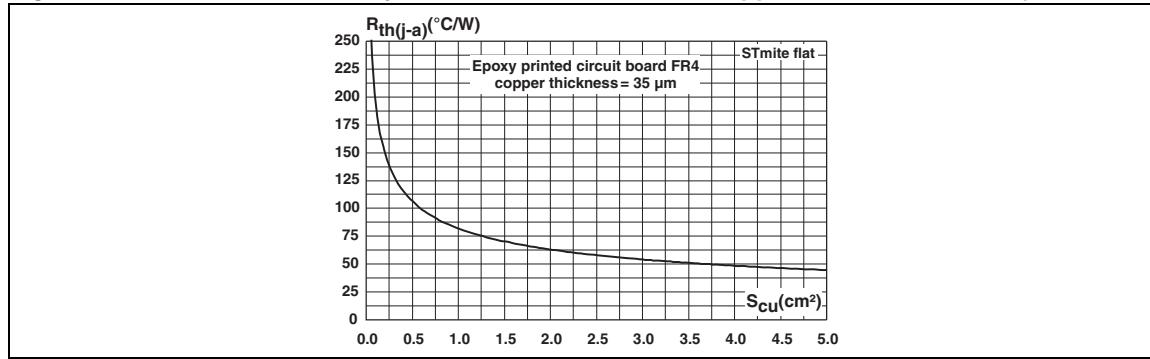


Figure 19. Thermal resistance junction to ambient versus copper surface under tab (STmite flat)



2 Package information

- Epoxy meets UL94, V0
- Band indicates cathode

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.
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Table 5. SMA dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.075	0.094
A2	0.05	0.20	0.002	0.008
b	1.25	1.65	0.049	0.065
c	0.15	0.40	0.006	0.016
D	2.25	2.90	0.089	0.114
E	4.80	5.35	0.189	0.211
E1	3.95	4.60	0.156	0.181
L	0.75	1.50	0.030	0.059

Figure 20. Footprint, dimensions in mm (inches)

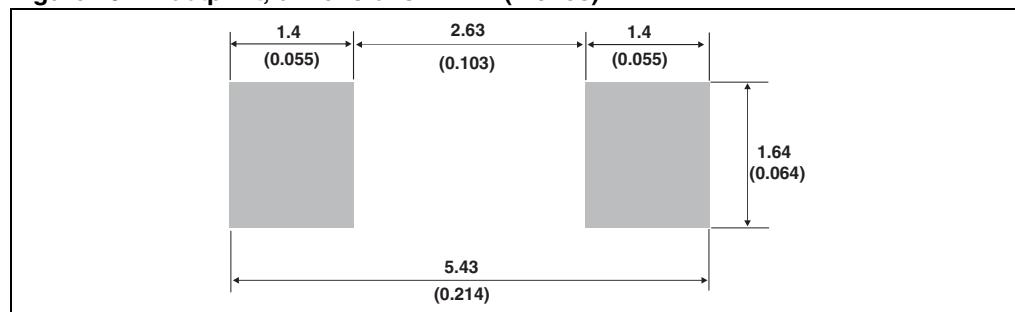
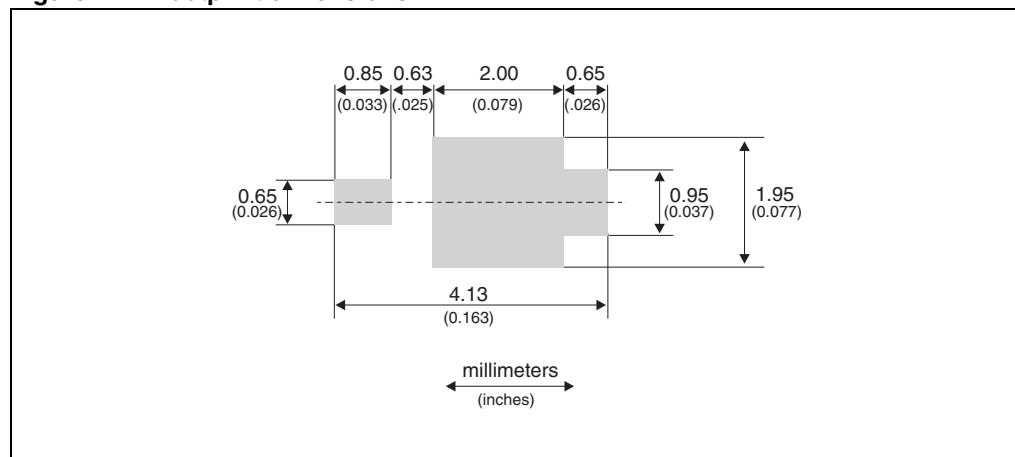


Table 6. STmite flat dimensions

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.80	0.85	0.95	0.031	0.033	0.037
b	0.40	0.55	0.65	0.016	0.022	0.026
b2	0.70	0.85	1.00	0.027	0.033	0.039
c	0.10	0.15	0.25	0.004	0.006	0.009
D	1.75	1.90	2.05	0.069	0.075	0.081
E	3.60	3.80	3.90	0.142	0.150	0.154
E1	2.80	2.95	3.10	0.110	0.116	0.122
L	0.50	0.55	0.80	0.020	0.022	0.031
L1	2.10	2.40	2.60	0.083	0.094	0.102
L2	0.45	0.60	0.75	0.018	0.024	0.030
L3	0.20	0.35	0.50	0.008	0.014	0.020

Figure 21. Footprint dimensions**Table 7. DO-41 (plastic) dimensions**

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.07	5.20	0.160	0.205
B	2.04	2.71	0.080	0.107
C	25.4		1	
D	0.71	0.86	0.028	0.034

3 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS1L60A	GB6	SMA	0.068 g	5000	Tape and reel
STPS1L60	STPS1L60	DO-41	0.34 g	2000	Ammopack
STPS1L60RL	STPS1L60	DO-41	0.34 g	5000	Tape and reel
STPS1L60MF	F1L6	STmite flat	0.016 g	12000	Tape and reel

4 Revision history

Table 9. Document revision history

Date	Revision	Changes
Jul-2003	5A	Last update.
Aug-2004	6	SMA package dimensions update. Reference A1 max changed from 2.70 mm (0.106 inc.) to 2.03 mm (0.080 inc).
25-Jun-2009	7	Added package STmite flat. Updated ECOPACK statement.
30-Sep-2009	8	Updated table 7 ref. " C ".

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